## DATASHEET

## 4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817-G Series



#### Features:

- Compliance Halogens Free
- (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm) • Current transfer ratio
- (CTR: 50~600% at IF = 5mA, VCE = 5V)
- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- Compliance with EU REACH.
- •The product itself will remain within RoHS compliant version
- UL and cUL approved(No.E214129)
- VDE approved (No.132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

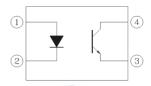
#### Description

The EL817-G series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector. They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

#### Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances





- **Pin Configuration**
- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

#### Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	١ <sub>F</sub>	60	mA
	Peak forward current (1us, pulse)	I <sub>FP</sub>	1	А
Input	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	D	100	mW
	Derating factor (above $T_a = 100$ °C)	P <sub>D</sub>	2.9	mW/°C
Output	Power dissipation	P <sub>C</sub>	150	mW
	Derating factor (above $T_a = 100^{\circ}C$ )		5.8	mW/°C
	Collector current	Ι <sub>C</sub>	50	mA
	Collector-Emitter voltage	V <sub>CEO</sub>	80	V
	Emitter-Collector voltage	$V_{ECO}$	7	V
Total Power Dissipation		P <sub>TOT</sub>	200	mW
Isolation Voltage*1		V <sub>ISO</sub>	5000	V rms
Operating Temperature		T <sub>OPR</sub>	-55 to 110	°C
Storage Te	emperature	T <sub>STG</sub>	-55 to 125	°C
Soldering Temperature* <sup>2</sup>		T <sub>SOL</sub>	260	°C

#### Notes:

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. \*2 For 10 seconds

#### Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

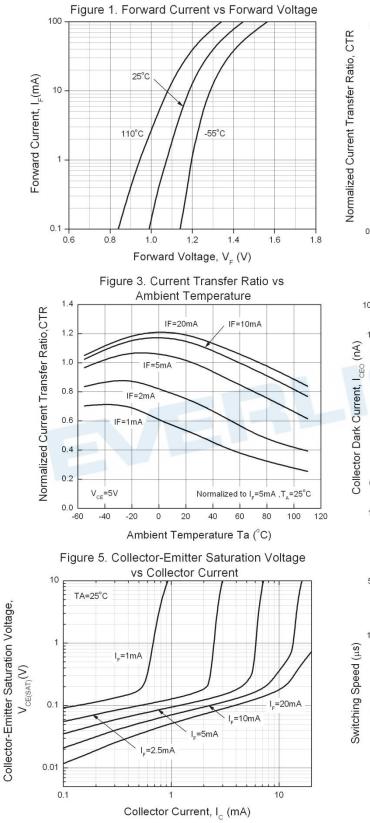
Input								
Parar	meter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Forward Voltage		V <sub>F</sub>	-	1.2	1.4	V	$I_F = 20 \text{mA}$	
Reverse Current		I <sub>R</sub>	-	-	10	μA	$V_R = 4V$	
Input capac	citance	C <sub>in</sub>	-	30	250	pF	V = 0, f = 1kHz	
Output								
Para	meter	Symbol	Min	Тур.	Max.	Unit	Condition	
Collector-Er current	nitter dark	I <sub>CEO</sub>	-	-	100	nA	$V_{CE} = 20V, I_F = 0mA$	
Collector-E breakdown		BV <sub>CEO</sub>	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$	
Emitter-Coll breakdown		$BV_{ECO}$	7	-	-	V	I <sub>E</sub> = 0.1mA	
Transfer Ch	aracteristics							
Para	meter	Symbol	Min	Тур.	Max.	Unit	Condition	
	EL817		50		600	%		
	EL817A		80	_	160			
Current	EL817B		130	-	260			
Transfer	EL817C	CTR	200	-	400		$I_F = 5 mA$ , $V_{CE} = 5 V$	
ratio	EL817D		300	-	600			
	EL817X		100	-	200			
	EL817Y		150	-	300			
Collector-E saturation v		V <sub>CE(sat)</sub>	-	0.1	0.2	V	$I_{F} = 20 mA$ , $I_{C} = 1 mA$	
	5							
Isolation rea	•	R <sub>IO</sub>	5×10 <sup>10</sup>	-	-	Ω	V <sub>IO</sub> = 500Vdc, 40~60% R.H.	
Isolation rea	sistance	R <sub>IO</sub> C <sub>IO</sub>	5×10 <sup>10</sup>	- 0.6	- 1.0	Ω pF		
	sistance						40~60% R.H.	
Floating ca	sistance	C <sub>IO</sub>		0.6		pF	$\frac{40 \sim 60\% \text{ R.H.}}{V_{IO} = 0, \text{ f} = 1 \text{MHz}}$ $V_{CE} = 5 \text{V}, \text{ I}_{C} = 2 \text{mA}}$	

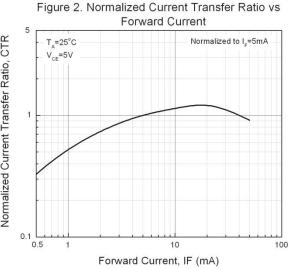
\* Typical values at T<sub>a</sub> = 25°C

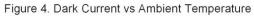
#### DATASHEET 4PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817-G Series

# EVERLIGHT

#### **Typical Electro-Optical Characteristics Curves**







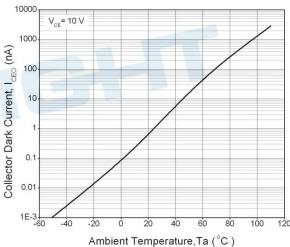
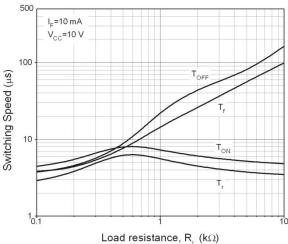


Figure 6. Switching Time vs Load Resistance



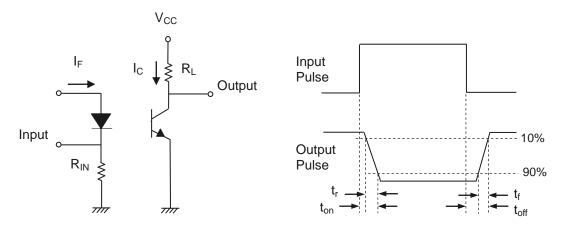


Figure 7. Switching Time Test Circuit & Waveforms



#### **Order Information**

#### Part Number

# EL817X(Y)(Z)-FVG

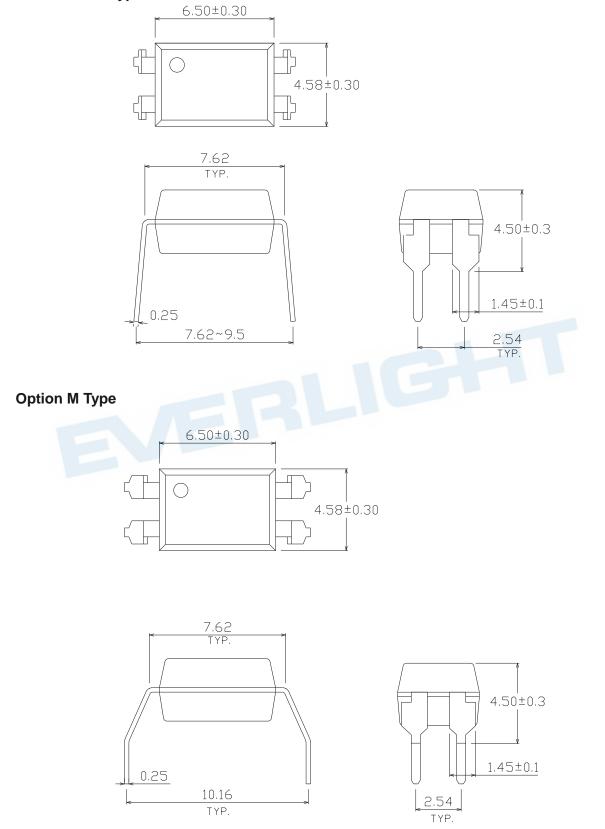
#### Note

- X = Lead form option (S1, S2, M or none)
- Y = CTR Rank (A, B, C, D, X, Y or none)
- Z = Tape and reel option (TU, TD or none)
- F = Lead frame option (F: Iron, None: copper)
- V = VDE safety (optional)
- G = Halogens free

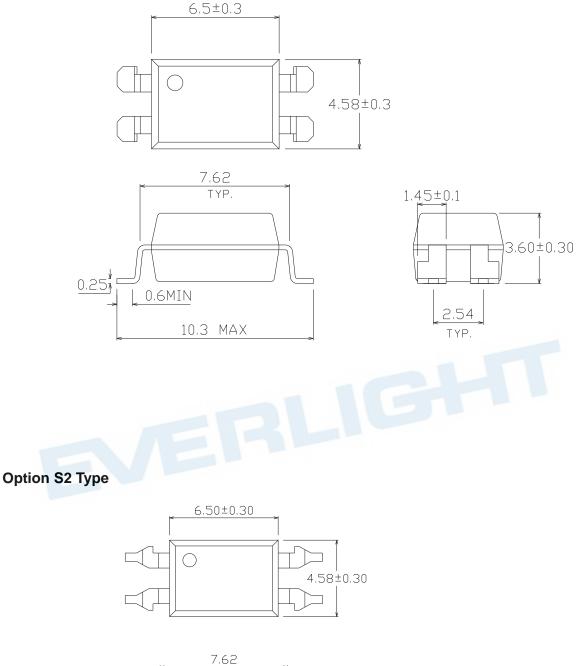
tandard DIP-4 Vide lead bend (0.4 inch spacing) urface mount lead form (low profile) + TU tape & reel option	100 units per tube 100 units per tube 1500 units per reel
urface mount lead form (low profile) + TU tape & reel option	1500 units per reel
	1500 units per reer
urface mount lead form (low profile) + TD tape & reel option	1500 units per reel
urface mount lead form (low profile) + TU tape & reel option	2000 units per reel
urface mount lead form (low profile) + TD tape & reel option	2000 units per reel
U	Inface mount lead form (low profile) + TU tape & reel option

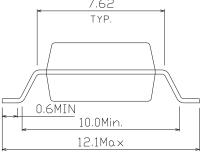
#### Package Dimension (Dimensions in mm)

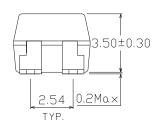
#### Standard DIP Type



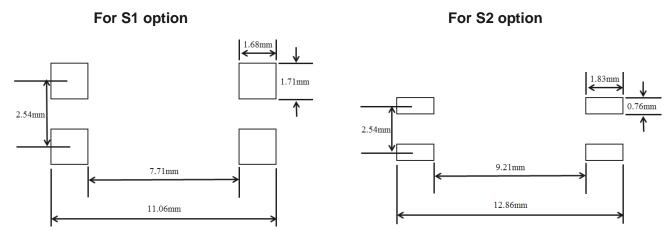
#### **Option S1 Type**







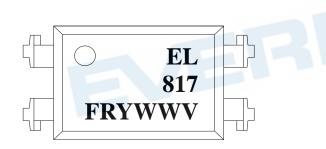
#### Recommended pad layout for surface mount leadform



#### Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

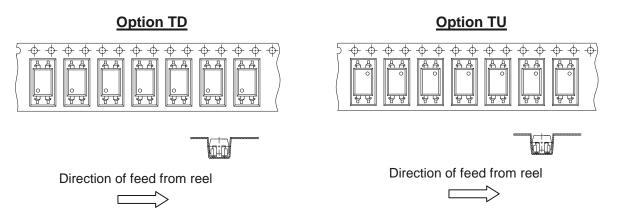
#### **Device Marking**



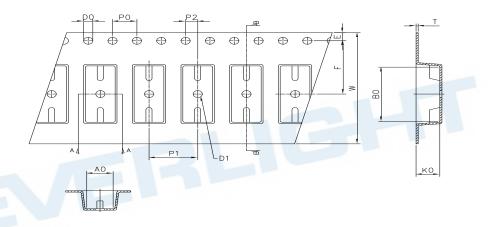
#### Notes

EL	denotes EVERLIGHT
817	denotes Device Number
F	denotes Factory Code (G: China and Green part)
R	denotes CTR Rank (A, B, C, D, X, Y or none)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

#### **Tape & Reel Packing Specifications**



#### **Tape dimensions**

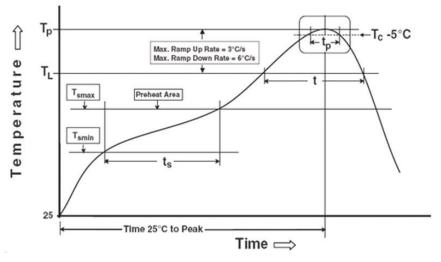


Dimension No.	Ao	Во	Do	D1	Е	F
Dimension (mm) S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	w	Ко
Dimension No. Dimension (mm) S1	<b>Po</b> 4.00±0.1	<b>P1</b> 8.00±0.1	<b>P2</b> 2.00±0.1	t 0.40±0.1	<b>W</b> 16.00±0.3	<b>Ko</b> 4.60±0.1

#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

.

#### Preheat

Temperature min  $(T_{smin})$ Temperature max  $(T_{smax})$ Time  $(T_{smin} \text{ to } T_{smax}) (t_s)$ Average ramp-up rate  $(T_{smax} \text{ to } T_p)$ **Other** Liquidus Temperature  $(T_L)$ Time above Liquidus Temperature  $(t_L)$ 

Peak Temperature (T<sub>P</sub>)

Time within 5 °C of Actual Peak Temperature:  $T_{\rm P}$  - 5 °C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature Reflow times

Reference: IPC/JEDEC J-STD-020D

**EVERLIGHT** 

150 °C 200°C

60-120 seconds 3 °C/second max

217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

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